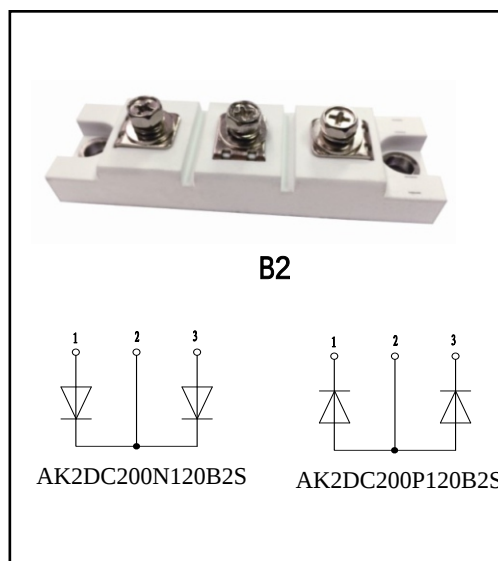


PRODUCT FEATURES

- ☑ Ultrafast Reverse Recovery Time
- ☑ Soft Reverse Recovery Characteristics
- ☑ Low Reverse Recovery Loss
- ☑ Low Forward Voltage
- ☑ High Surge Current Capability
- ☑ Low Inductance Package

APPLICATIONS

- ☑ Inversion Welder
- ☑ Uninterruptible Power Supply (UPS)
- ☑ Plating Power Supply
- ☑ Ultrasonic Cleaner and Welder
- ☑ Converter & Chopper
- ☑ Power Factor Correction (PFC) Circuit



ABSOLUTE MAXIMUM RATINGS

$T_C=25^{\circ}\text{C}$ unless otherwise specified

Symbol	Parameter	Test Conditions	Values	Unit
V_R	Maximum D.C. Reverse Voltage		1200	V
V_{RRM}	Maximum Repetitive Reverse Voltage		1200	V
$I_{F(AV)}$	Average Forward Current	$T_C=75^{\circ}\text{C}$, Per Diode	100	A
		$T_C=85^{\circ}\text{C}$, 20KHz, Per Diode	75	A
$I_{F(RMS)}$	RMS Forward Current	$T_C=75^{\circ}\text{C}$, Per Diode	150	A
I_{FSM}	Non-Repetitive Surge Forward Current	$T_J=45^{\circ}\text{C}$, $t=10\text{ms}$, 50Hz, Sine	1100	A
		$T_J=45^{\circ}\text{C}$, $t=8.3\text{ms}$, 60Hz, Sine	1200	A
I^2t	I^2t (For Fusing)	$T_J=45^{\circ}\text{C}$, $t=10\text{ms}$, 50Hz, Sine	6050	A^2s
		$T_J=45^{\circ}\text{C}$, $t=8.3\text{ms}$, 60Hz, Sine	7200	A^2s
P_D	Power Dissipation		280	W
T_J	Junction Temperature		-40 to +150	$^{\circ}\text{C}$
T_{STG}	Storage Temperature Range		-40 to +125	$^{\circ}\text{C}$
V_{isol}	Insulation Test Voltage	AC, $t=1\text{min}$	3000	V
Torque	Module-to-Sink	Recommended (M5)	2.5~4	Nm
Torque	Module Electrodes	Recommended (M5)	2.5~4	Nm
$R_{\theta C}$	Thermal Resistance	Junction-to-Case	0.44	$^{\circ}\text{C} / \text{W}$
Weight			110	g

ELECTRICAL CHARACTERISTICS
 $T_C=25^{\circ}\text{C}$ unless otherwise specified

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{RM}	Reverse Leakage Current	$V_R=1200\text{V}$	--	--	20	μA
		$V_R=1200\text{V}, T_J=125^{\circ}\text{C}$	--	--	200	μA
V_F	Forward Voltage	$I_F=100\text{A}$	--	1.6	--	V
		$I_F=100\text{A}, T_J=125$	--	1.38	--	V
t_{rr}	Reverse Recovery Time I	$I_F=1\text{A}, V_R=30\text{V}, di_F/dt=-200\text{A}/\mu\text{s}$	--	55	--	ns
t_{rr}	Reverse Recovery Time V	$V_R=600\text{V}, I_F=100\text{A}$	--	135	--	ns
I_{RRM}	Max. Reverse Recovery Current	$di_F/dt=-200\text{A}/\mu\text{s}, T_J=25^{\circ}\text{C}$	--	10	--	A
t_{rr}	Reverse Recovery Time	$V_R=600\text{V}, I_F=100\text{A}$	--	380	--	ns
I_{RRM}	Max. Reverse Recovery Current	$di_F/dt=-200\text{A}/\mu\text{s}, T_J=125^{\circ}\text{C}$	--	21	--	A

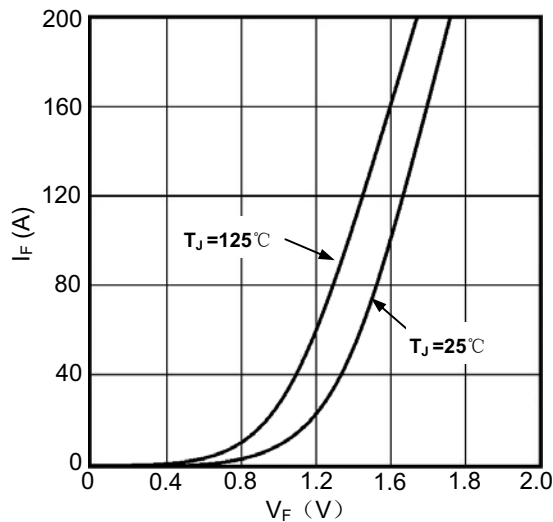
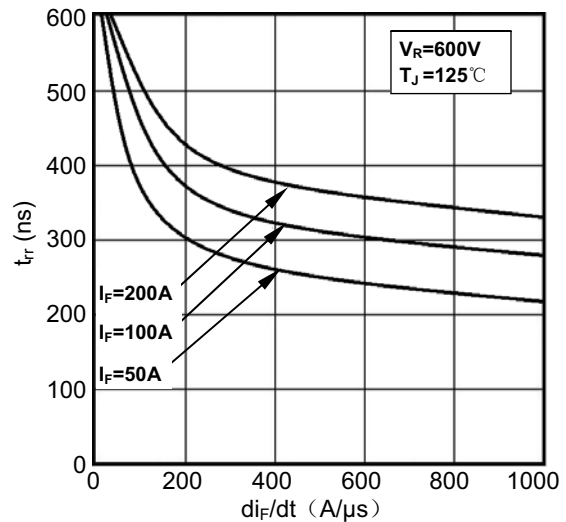
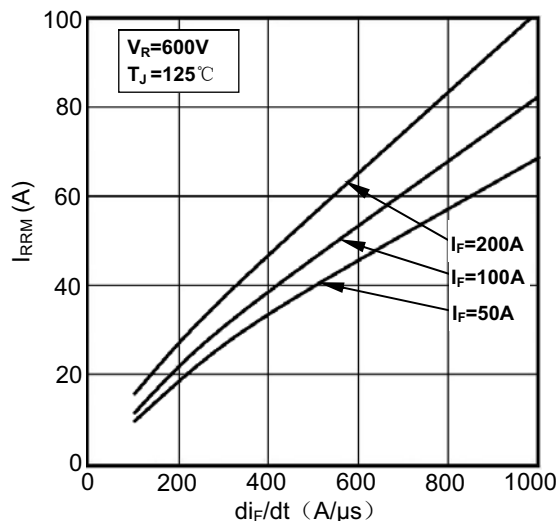
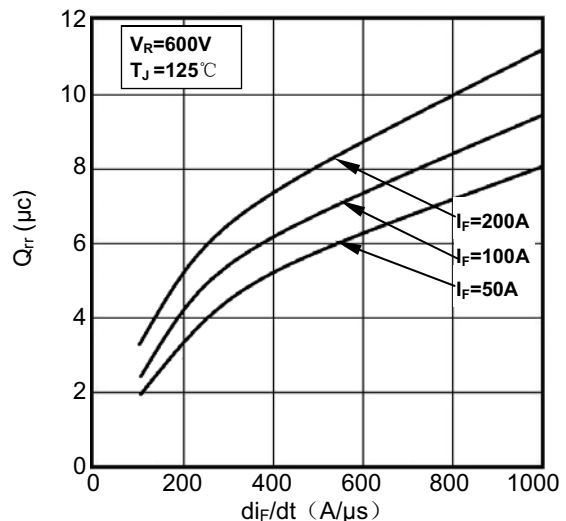


Figure1. Forward Voltage Drop vs Forward Current


 Figure2. Reverse Recovery Time vs di_F/dt

 Figure3. Reverse Recovery Current vs di_F/dt

 Figure4. Reverse Recovery Charge vs di_F/dt

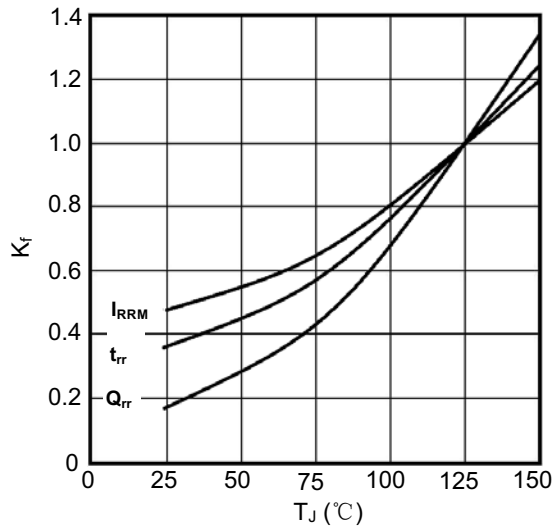


Figure5. Dynamic Parameters vs Junction Temperature

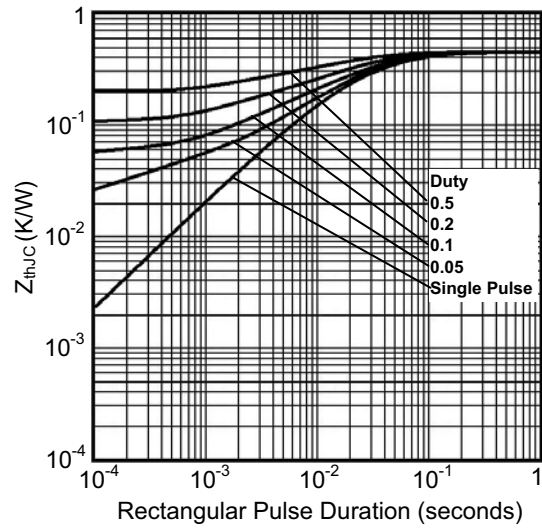
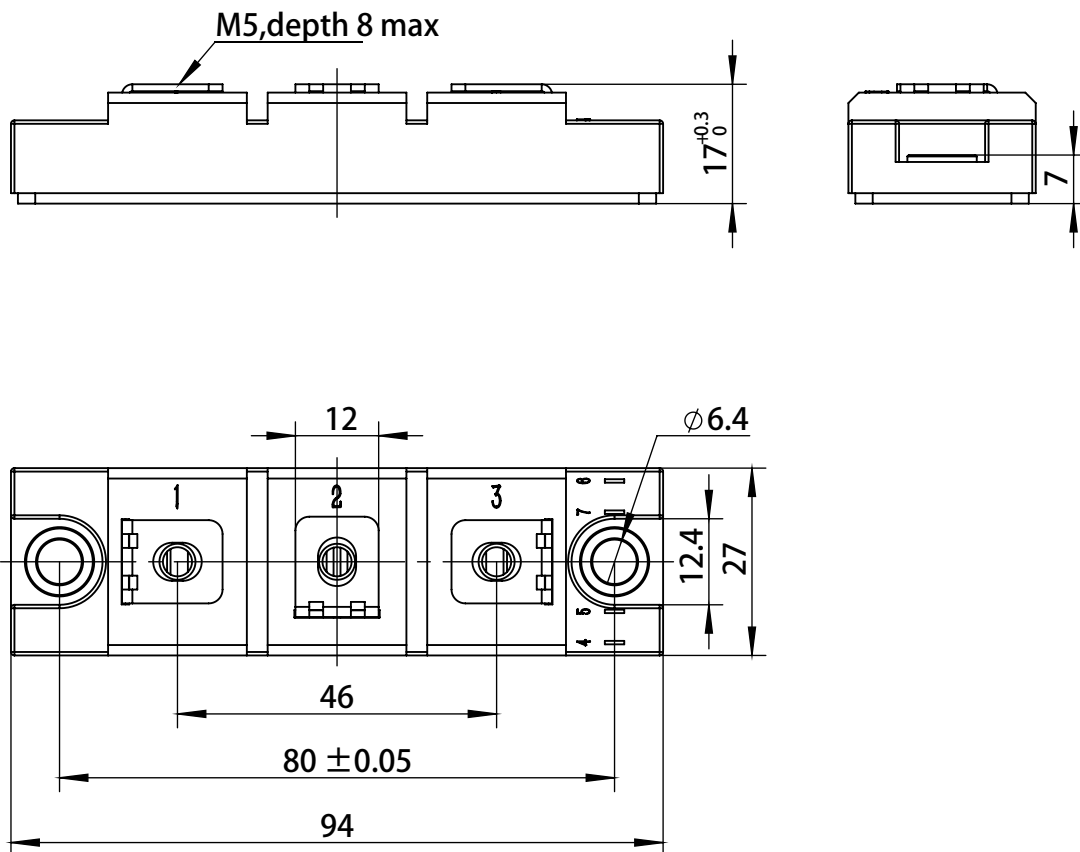


Figure6. Transient Thermal Impedance

Package Outlines



Unit:mm